UTC UNISONIC TECHNOLOGIES CO., LTD

UT2301Z **Power MOSFET**

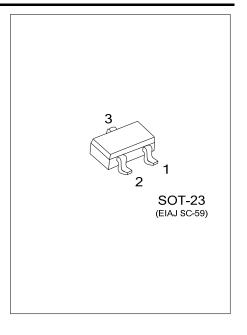
-2.8A, -20V P-CHANNEL **ENHANCEMENT MODE POWER MOSFET**

DESCRIPTION

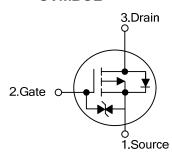
The UTC UT2301Z is a P-channel enhancement mode power MOSFET with fast switching speed, low on-resistance and favorable stabilization. It can be used in commercial and industrial surface mount applications and suited for low voltage applications such as DC/DC converters.

FEATURES

- * Very High Density Cell Design for Low On-Resistance
- * Very Good Thermal and Electrical Capabilities



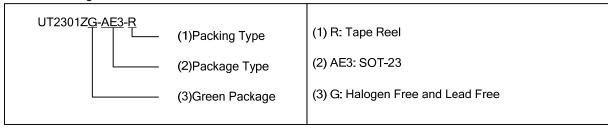
SYMBOL



ORDERING INFORMATION

Ordering Number	Package	Pin Assignment			Dooking	
		1	2	3	Packing	
UT2301ZG-AE3-R	SOT-23	S	G	D	Tape Reel	

Note: Pin Assignment: S: Source G: Gate D: Drain



MARKING



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■ **ABSOLUTE MAXIMUM RATINGS** (T_A = 25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATING	UNITS
Drain-Source Voltage	V_{DS}	-20	V
Gate-Source Voltage	V_{GS}	±8	V
Continuous Drain Current	I _D	-2.8	Α
Pulsed Drain Current (Note 2, 3)	I _{DM}	-10	Α
Total Power Dissipation (Note 4)	P _D	1.25	W
Junction Temperature	TJ	+150	°C
Storage Temperature	T _{STG}	-55 ~ + 150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Pulse width limited by $T_{J(MAX)}$
- 3. Pulse width ≤300µs, duty cycle ≤2 %
- 4. Surface mounted on 1 in 2 copper pad of FR4 board.

■ THERMAL DATA (Note)

PARAMETER	SYMBOL	RATING	UNIT
Junction to Ambient	θ_{JA}	100	°C/W

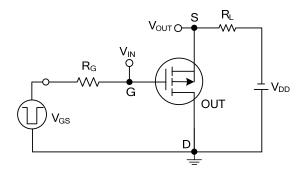
Notes: Surface mounted on FR4 board t ≤ 5%sec

■ ELECTRICAL CHARACTERISTICS (I_D=-2.3A , T_A=25°C, unless otherwise specified)

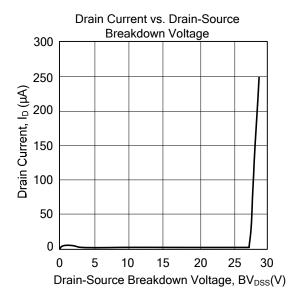
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-20			V	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-16V, V _{GS} =0V			-1.0	μΑ	
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±8V, V _{DS} =0V			±5	μΑ	
ON CHARACTERISTICS							
Gate Threshold Voltage	$V_{GS(TH)}$	V _{DS} =V _{GS} , I _D =-250uA	-0.45			V	
Static Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-2.8A		95	130	mΩ	
		V _{GS} =-2.5V, I _D =-2.0A		122	190	mΩ	
On-State Drain Current	I _{D(ON)}	V _{DS} =-5 V, V _{GS} =-10V	-6			Α	
Forward Tran conductance	g FS	V _{DS} =-5 V, I _D =-2.8A		6.5		S	
DYNAMIC CHARACTERISTICS							
Input Capacitance	C _{ISS}			447		pF	
Output Capacitance	Coss	V_{GS} =0V, V_{DS} =-6V, f=1.0MHz		127		pF	
Reverse Transfer Capacitance	C _{RSS}			80		pF	
SWITCHING CHARACTERISTICS							
Total Gate Charge (Note)	Q_G	\\ - C\\ \\ - 4.5\\		5.4	10	nC	
Gate-Source Charge	Q_GS	V _{DS} =-6V, V _{GS} =-4.5V,		8.0		nC	
Gate-Drain Charge	Q_GD	ID2.8A		1.1		nC	
Turn-ON Delay Time (Note)	t _{D(ON)}			5	25	ns	
Turn-ON Rise Time	t _R	V _{DD} =-6V, V _{GEN} =-4.5V,		19	60	ns	
Turn-OFF Delay Time	t _{D(OFF)}	I_D =-1A, R_G =6 Ω , R_L =6 Ω		95	110	ns	
Turn-OFF Fall Time	t _F			65	80	ns	
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS							
Diode Forward Voltage (Note)	V_{SD}	I _S =-1.6 A, V _{GS} =0 V		-0.8	-1.2	V	
Maximum Diode Forward Current	Is				-1.6	Α	

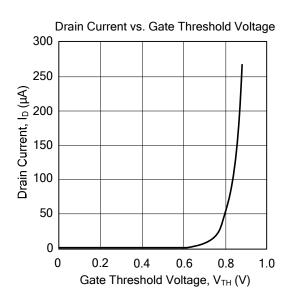
Notes: Pulse width ≤300µs, Duty Cycle ≤2%

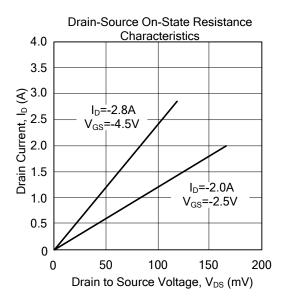
SWITCHING TEST CIRCUIT

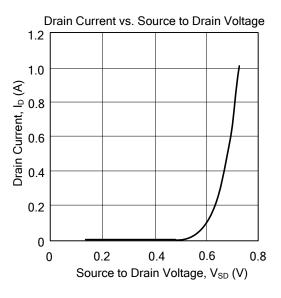


■ TYPITAL CHARACTERISTICS









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